VS-30.PF0.-M3 Series

Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 30 A



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PRIMARY CHARACTERISTICS					
I _{F(AV)}	30 A				
V _R	200 V, 400 V, 600 V				
V _F at I _F	1.41 V				
I _{FSM}	320 A				
t _{rr}	60 ns				
T _J max.	150 °C				
Package	TO-247AC 2L, TO-247AC 3L				
Circuit configuration	Single				
Snap factor	0.6				

FEATURES

- Glass passivated pellet chip junction
- 150 °C max. operating junction temperature
- Low forward voltage drop and short reverse recovery time
- Designed and qualified according to ${\sf JEDEC}^{\textcircled{B}}{-}{\sf JESD}$ 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-30EPF06-M3 and VS-30APF06-M3 soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

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MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Sinusoidal waveform	30	A			
V _{RRM}		200 to 600	V			
I _{FSM}		320	A			
V _F	10 A, T _J = 25 °C	1.2	V			
t _{rr}	1 A, 100 A/µs	60	ns			
TJ		-40 to +150	°C			

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA				
VS-30EPF02-M3, VS-30APF02-M3	200	300					
VS-30EPF04-M3, VS-30APF04-M3	400	500	5				
VS-30EPF06-M3, VS-30APF06-M3	600	700					

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ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum average forward current	I _{F(AV)}	T_C = 98 °C, 180° conduction half sine wave	30				
Maximum peak one cycle non-repetitive surge current	I _{FSM}	10 ms sine pulse, rated V_{RRM} applied	270	А			
		10 ms sine pulse, no voltage reapplied	320				
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V_{RRM} applied	365	A ² s			
Maximum From fusing		10 ms sine pulse, no voltage reapplied	515	A-5			
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	5150	A²√s			

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS		
Maximum forward voltage drop	V _{FM}	30 A, T _J = 25 °C		1.41	V		
Forward slope resistance	r _t	T.I = 150 °C		12.5	mΩ		
Threshold voltage	V _{F(TO)}	1j = 150 C		0.9	V		
		T _J = 25 °C		0.1	mA		
Maximum reverse leakage current	IRM	T _J = 150 °C	V _R = Rated V _{RRM}	5.0	ША		

RECOVERY CHARACTERISTICS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Reverse recovery time	t _{rr}	l⊨ at 20 A _{nk}	160	ns	I _{FM}		
Reverse recovery current	I _{rr}	l _F at 20 A _{pk} 100 A/μs	10	А	$t_a \mid t_b$		
Reverse recovery charge	Q _{rr}	25 °C	1.25	μC	$\frac{\text{dir}}{\text{dt}}$		
Snap factor	S	Typical	0.6		I V I _{RM(REC)}		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range		T _J , T _{Stg}		-40 to +150	°C		
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	0.8			
Maximum thermal resis junction to ambient	tance,	R _{thJA}		40	°C/W		
Maximum thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.2			
Approximate weight				6	g		
				0.21	oz.		
Mounting torque minimum maximum				6 (5)	kgf ⋅ cm		
				12 (10)	(lbf · in)		
				30EF	F02		
Marking device			Case style TO-247AC 2L	30EPF04			
				30EP	F06		
				30AF	F02		
			Case style TO-247AC 3L	30APF04			
				30APF06			

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Fig. 1 - Current Rating Characteristics



Fig. 2 - Current Rating Characteristics



Fig. 3 - Forward Power Loss Characteristics



Fig. 4 - Forward Power Loss Characteristics







Fig. 6 - Maximum Non-Repetitive Surge Current

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Fig. 7 - Forward Voltage Drop Characteristics



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Fig. 8 - Recovery Time Characteristics, $T_J = 25 \ ^{\circ}C$



Fig. 9 - Recovery Time Characteristics, $T_J = 150 \ ^\circ C$



Fig. 10 - Recovery Charge Characteristics, $T_J = 25 \degree C$



Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

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Fig. 12 - Recovery Current Characteristics, $T_J = 25 \ ^{\circ}C$



Fig. 13 - Recovery Current Characteristics, $T_J = 150 \ ^\circ C$



Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

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VS-30.PF0.-M3 Series

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ORDERING INFORMATION TABLE

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			_	_	_		
Device code	VS-	30	E	P	F	06	-M3
	(1)	(2)	(3)	(4)	(5)	(6)	(7)
	1 -	Visł	nay Sem	niconduc	ctors pro	duct	
	2 -	Cur	rent rati	ng (30 =	: 30 A)		
	3 -	Circ	uit confi	iguratior	n:		
		E =	single d	liode, 2	pins		
		A =	single d	liode, 3	pins		
	4 -	Pac	kage:				
		P =	TO-247	AC 3L /	TO-247	AC 2L	
	5 -	Тур	e of silio	con:			
		F = fast recovery 02 = 200 V					
	6 -	Volt	age cod	le x 100	= V _{RRM}	I	- 04 =
	7 -	Env	ironmer	ntal digit	:		06 =
		-M3	= halog	jen-free	, RoHS-	complia	ant, and

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-30EPF02-M3	25	500	Antistatic plastic tubes					
VS-30APF02-M3	25	500	Antistatic plastic tubes					
VS-30EPF04-M3	25	500	Antistatic plastic tubes					
VS-30APF04-M3	25	500	Antistatic plastic tubes					
VS-30EPF06-M3	25	500	Antistatic plastic tubes					
VS-30APF06-M3	25	500	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS					
Dimensions	TO-247AC 2L	www.vishay.com/doc?96144			
Dimensions	TO-247AC 3L	www.vishay.com/doc?96138			
Part marking information	TO-247AC 2L	www.vishay.com/doc?95648			
	TO-247AC 3L	www.vishay.com/doc?95007			

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